

BC636/638/640

Switching and Amplifier Applications

• Complement to BC635/637/639



PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings Ta=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CER}	Collector-Emitter Voltage at R _{BE} =1KΩ		
	: BC636	-45	V
	: BC638	-60	V
	: BC640	-100	V
V _{CES}	Collector-Emitter Voltage		
	: BC636	-45	V
	: BC638	-60	V
	: BC640	-100	V
V _{CEO}	Collector-Emitter Voltage		
	: BC636	-45	V
	: BC638	-60	V
	: BC640	-80	V
V _{EBO}	Emitter-Base Voltage	-5	V
I _C	Collector Current	-1	Α
I _{CP}	Peak Collector Current	-1.5	Α
I _B	Base Current	-100	mA
P _C	Collector Power Dissipation	1	W
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-65 ~ 150	°C

Electrical Characteristics T_a =25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C = -10mA, I _B =0				
	: BC636		-45			V
	: BC638		-60			V
	: BC640		-80			V
I _{CBO}	Collector Cut-off Current	V _{CB} = -30V, I _E =0			-0.1	μΑ
I _{EBO}	Emitter Cut-off Current	V_{EB} = -5V, I_{C} =0			-10	μΑ
h _{FE1}	DC Current Gain : All	V_{CE} = -2V, I_{C} = -5mA	25			
h_{FE2}	: BC636	$V_{CE} = -2V, I_{C} = -150 \text{mA}$	40		250	
	: BC638/BC640		40		160	
h_{FE3}	: All	$V_{CE} = -2V, I_{C} = -500 \text{mA}$	25			
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C = -500mA, I _B = -50mA			-0.5	V
V _{BE} (on)	Base-Emitter On Voltage	V_{CE} = -2V, I_{C} = -500mA			-1	V
f _T	Current Gain Bandwidth Product	V_{CE} = -5V, I_{C} = -10mA, f=50MHz		100		MHz

Typical Characteristics

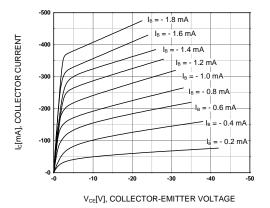


Figure 1. Static Characteristic

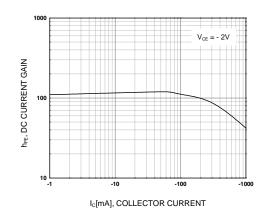


Figure 2. DC current Gain

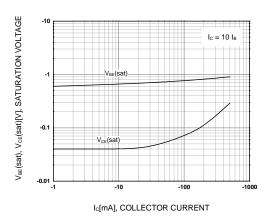


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

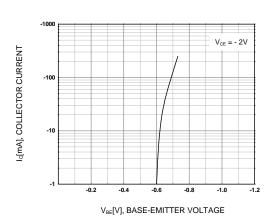


Figure 4. Base-Emitter On Voltage

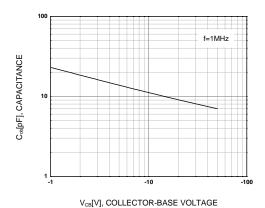
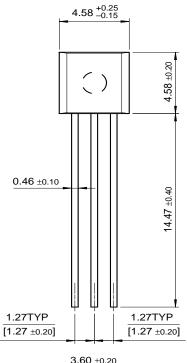
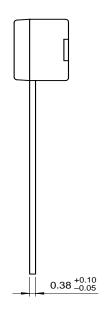


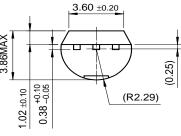
Figure 5. Collector Output Capacitance

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TO-92







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